NPN Epitaxial Planar Silicon Transistor



2SC5291

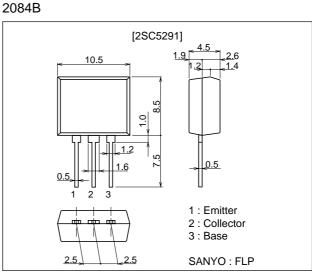
High-Voltage Switching Applications

Features

- Adoption of FBET, MBIT processes.
- Large current capacity.
- Can be provided in taping.
- 9.5mm onboard mounting height.

Package Dimensions

unit : mm



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		180	V
Collector-to-Emitter Voltage	VCEO		160	V
Emitter-to-Base Voltage	VEBO		6	V
Collector Current	IC		1.5	A
Collector Current (Pulse)	ICP		2.5	A
Base Current	IB		300	mA
Collector Dissipation	PC		1.5	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} =120V, I _E =0			1.0	μA
Emitter Cutoff Current	IEBO	VEB=4V, IC=0			1.0	μA

Continued on next page.

- Any and all SANYO products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your SANYO representative nearest you before using any SANYO products described or contained herein in such applications.
- SANYO assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO products described or contained herein.

SANYO Electric Co., Ltd. Semiconductor Company TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN Continued from preceding page.

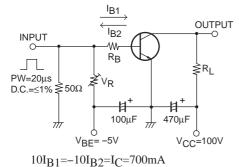
Parameter	Symbol	Conditions	Ratings			11-34
			min	typ	max	Unit
DC Current Gain	hFE1	V _{CE} =5V, I _C =100mA	100		400	
	hFE2	V _{CE} =5V, I _C =10mA	90			
Gain-Bandwidth Product	fT	VCE=10V, IC=50mA		120		MHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		14		pF
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)	IC=500mA, IB=50mA		0.13	0.45	V
Base-to-Emitter Saturation Voltage	VBE(sat)	IC=500mA, IB=50mA		0.85	1.2	V
Turn-ON Time	ton	See specified Test Circuit		4.0		ns
Storage Time	tstg	See specified Test Circuit		1.2		μs
Fall Time	tf	See specified Test Circuit		8.0		ns

 * : The 2SC5291 is classified by 100mA hFE as follows :

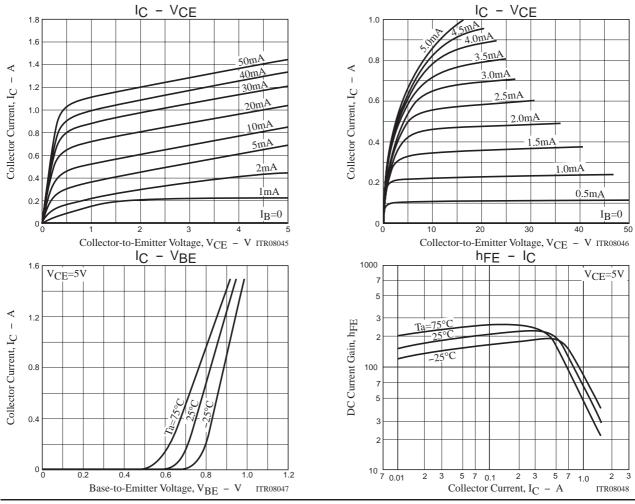
Rank R S T

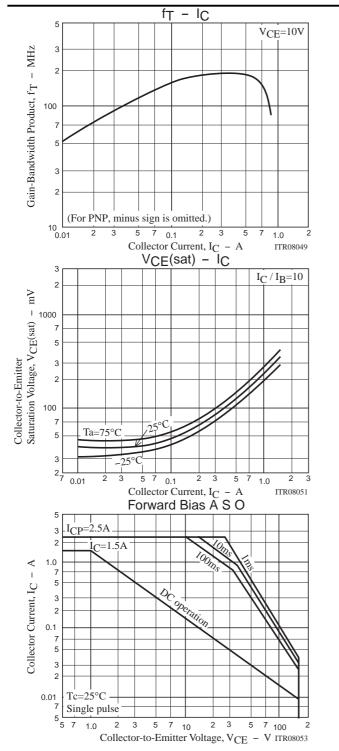
hFE 100 to 200 140 to 280 200 to 400

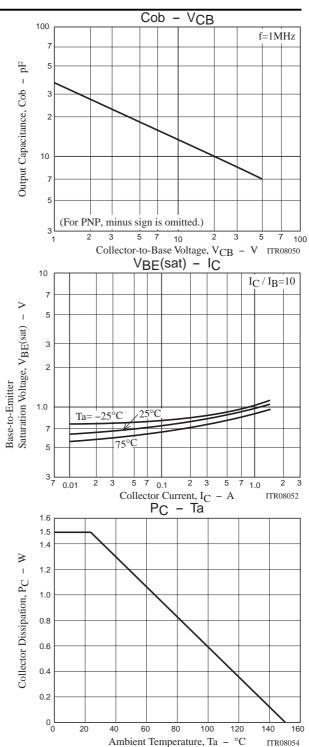
Switching Time Test Circuit



 $R_L{=}140\Omega,\,R_B{=}14\Omega$ at $I_C{=}700mA$







- Specifications of any and all SANYO products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- SANYO Electric Co., Ltd. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of SANYO Electric Co., Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO product that you intend to use.
- Information (including circuit diagrams and circuit parameters) herein is for example only ; it is not guaranteed for volume production. SANYO believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.

This catalog provides information as of January, 2001. Specifications and information herein are subject to change without notice.